



UNITED STATES PATENT AND TRADEMARK OFFICE

UNITED STATES DEPARTMENT OF COMMERCE
United States Patent and Trademark Office
Address: COMMISSIONER FOR PATENTS
P.O. Box 1450
Alexandria, Virginia 22313-1450
www.uspto.gov

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
-----------------	-------------	----------------------	---------------------	------------------

10/581,754

06/05/2006

Cheng Zheng

42P23020

8501

45209

7590

07/08/2009

INTEL/BSTZ

BLAKELY SOKOLOFF TAYLOR & ZAFMAN LLP

1279 OAKMEAD PARKWAY

SUNNYVALE, CA 94085-4040

EXAMINER

ROJAS, MIDYS

ART UNIT

PAPER NUMBER

2185

MAIL DATE

DELIVERY MODE

07/08/2009

PAPER

Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

Office Action Summary	Application No.	Applicant(s)	
	10/581,754	ZHENG ET AL.	
	Examiner	Art Unit	
	MIDYS ROJAS	2185	

-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --

Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) OR THIRTY (30) DAYS, WHICHEVER IS LONGER, FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

Status

- 1) ☒ Responsive to communication(s) filed on 23 April 2009.
- 2a) ☐ This action is **FINAL**. 2b) ☒ This action is non-final.
- 3) ☐ Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

Disposition of Claims

- 4) ☒ Claim(s) 1-16 and 25-29 is/are pending in the application.
- 4a) Of the above claim(s) _____ is/are withdrawn from consideration.
- 5) ☐ Claim(s) _____ is/are allowed.
- 6) ☒ Claim(s) 1-16 and 25-29 is/are rejected.
- 7) ☐ Claim(s) _____ is/are objected to.
- 8) ☐ Claim(s) _____ are subject to restriction and/or election requirement.

Application Papers

- 9) ☐ The specification is objected to by the Examiner.
- 10) ☒ The drawing(s) filed on 05 June 2006 is/are: a) ☒ accepted or b) ☐ objected to by the Examiner.
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).
- 11) ☐ The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.

Priority under 35 U.S.C. § 119

- 12) ☐ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
- a) ☐ All b) ☐ Some * c) ☐ None of:
1. ☐ Certified copies of the priority documents have been received.
 2. ☐ Certified copies of the priority documents have been received in Application No. _____.
 3. ☐ Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).

* See the attached detailed Office action for a list of the certified copies not received.

Attachment(s)

- | | |
|--|---|
| 1) <input checked="" type="checkbox"/> Notice of References Cited (PTO-892) | 4) <input type="checkbox"/> Interview Summary (PTO-413) |
| 2) <input type="checkbox"/> Notice of Draftsperson's Patent Drawing Review (PTO-948) | Paper No(s)/Mail Date. _____ |
| 3) <input type="checkbox"/> Information Disclosure Statement(s) (PTO/SB/08) | 5) <input type="checkbox"/> Notice of Informal Patent Application |
| Paper No(s)/Mail Date _____ | 6) <input type="checkbox"/> Other: _____ |

DETAILED ACTION

Response to Arguments

1. Applicant's arguments, filed 4/23/2009, have been fully considered and are persuasive. Therefore, the rejection has been withdrawn. However, upon further consideration, a new ground(s) of rejection is made in view of Eilert (US 6,909,645).

Claim Rejections - 35 USC § 112

2. The rejection of claims 12 and 21 under 35 U.S.C. 112, second paragraph is withdrawn in view of applicant's amendments.

3. The rejection of claims 9-11, 18-20, 14-16, and 22-24 under 35 U.S.C. 112, second paragraph is withdrawn in view of applicant's amendments.

Claim Rejections - 35 USC § 101

4. The rejection of claims 12 and 21 under 35 U.S.C. 101 is withdrawn in view of applicant's amendments.

Claim Rejections - 35 USC § 103

5. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

6. Claims 1-2, 6-8, 12-13, and 25-26 are rejected under 35 U.S.C. 103(a) as being obvious over Eilert (US 6,909,645) in view of Sinclair (US 2007/0088904).

Regarding Claim 1, Eilert discloses a memory device comprising: an array of memory locations implemented as bit-alterable, non-volatile memory configured as a plurality of blocks of memory locations (bit-alterable phase change memory, Col. 1, line 65 – Col. 2, line 6); and control circuitry coupled with the array of memory locations (processors 52 as shown in Figure 4).

Eilert does not disclose a control circuitry that causes a block of data to be stored in the array of memory spanning a boundary between a first block of memory locations and a second block of memory locations.

Sinclair discloses a control circuitry that causes a block of data to be stored in the array of memory spanning a boundary between a first block of memory locations and a second block of memory locations (paragraph 0009 wherein a transformed data unit may be split into two or more data groups by a physical block boundary). It would have been obvious to one of ordinary skill in the art the time the invention was made to modify the memory of Eilert to store data spanning two block of memory by splitting the data with the physical block boundary, as taught by Sinclair, since doing so allows for the efficient use of memory capacity.

Regarding Claim 2, Eilert in view of Sinclair discloses the memory device wherein the control circuitry causes a header having an indication of a memory location corresponding to the block of data (additional amount of data storing ECC and overhead

Art Unit: 2185

related to the user data and the temporary cell group in which it is stored, paragraph 0004) to be stored within the first block of memory locations (paragraph 0009 wherein a transformed data unit may be split into two or more data groups by a physical block boundary and wherein a header is stored at the beginning of the block of data and therefore, it must be stored within the first data group when the block is split by the physical block boundary).

Regarding Claim 6, Eilert in view of Sinclair discloses the memory device wherein the block of data comprises system data to be used during system initialization and further wherein the block of data is stored in a pre-selected location within the memory array for all initialization sequences (boot code for initialization is stored within ROM 29, paragraph 0038 of Sinclair).

Regarding Claim 7, Eilert discloses a method comprising:

receiving data to be stored in a bit-alterable, non-volatile memory configured as a plurality of blocks of memory locations (bit-alterable phase change memory, Col. 1, line 65 – Col. 2, line 6); and control circuitry coupled with the array of memory locations (such as that in processors 52 as shown in Figure 4).

Eilert does not disclose a causing a block of data to be stored in the array of memory spanning a boundary between a first block of memory locations and a second block of memory locations.

Art Unit: 2185

Sinclair discloses causing a block of data to be stored in the array of memory spanning a boundary between a first block of memory locations and a second block of memory locations (paragraph 0009 wherein a transformed data unit may be split into two or more data groups by a physical block boundary). It would have been obvious to one of ordinary skill in the art the time the invention was made to modify the memory of Eilert to store data spanning two block of memory by splitting the data with the physical block boundary, as taught by Sinclair, since doing so allows for the efficient use of memory capacity.

Regarding Claim 8, Eilert in view of Sinclair discloses the method further comprising causing a header having an indication of a memory location corresponding to the block of data (additional amount of data storing ECC and overhead related to the user data and the temporary cell group in which it is stored, paragraph 0004) to be stored within the first block of memory locations (paragraph 0009 wherein a transformed data unit may be split into two or more data groups by a physical block boundary and wherein a header is stored at the beginning of the block of data and therefore, it must be stored within the first data group when the block is split by the physical block boundary).

Regarding Claim 12, Eilert discloses an article comprising a computer-readable medium having stored thereon instructions that, when executed, cause one or more processors to: receive data to be stored in a bit-alterable, non-volatile memory

Art Unit: 2185

configured as a plurality of blocks of memory locations (bit-alterable phase change memory, Col. 1, line 65 – Col. 2, line 6); and control circuitry coupled with the array of memory locations (such as that in processors 52 as shown in Figure 4).

Eilert does not disclose a causing a block of data to be stored in the array of memory spanning a boundary between a first block of memory locations and a second block of memory locations.

Sinclair discloses causing a block of data to be stored in the array of memory spanning a boundary between a first block of memory locations and a second block of memory locations (paragraph 0009 wherein a transformed data unit may be split into two or more data groups by a physical block boundary). It would have been obvious to one of ordinary skill in the art the time the invention was made to modify the memory of Eilert to store data spanning two block of memory by splitting the data with the physical block boundary, as taught by Sinclair, since doing so allows for the efficient use of memory capacity.

Regarding Claim 13, Eilert in view of Sinclair discloses the article further comprising instructions that, when executed, cause the one or more processors to cause a header (additional amount of data storing ECC and overhead related to the user data and the temporary cell group in which it is stored, paragraph 0004) having an indication of a memory location corresponding to the data fragment to be stored within the first block of memory locations (paragraph 0009 wherein a transformed data unit may be split into two or more data groups by a physical block boundary and wherein a

header is stored at the beginning of the block of data and therefore, it must be stored within the first data group when the block is split by the physical block boundary).

Regarding Claim 25, Eilert discloses a system comprising:

an antenna (for reception and transmission through wireless interface, 56, Fig 4);

a memory system coupled with the antenna, the memory system having an array of memory locations implemented as bit-alterable, non-volatile memory configured as a plurality of blocks of memory locations (bit-alterable phase change memory, Col. 1, line 65 – Col. 2, line 6); and control circuitry coupled with the array of memory locations (such as that in processors 52 as shown in Figure 4).

Eilert does not disclose a control circuitry that causes a block of data to be stored in the array of memory spanning a boundary between a first block of memory locations and a second block of memory locations.

Sinclair discloses a control circuitry that causes a block of data to be stored in the array of memory spanning a boundary between a first block of memory locations and a second block of memory locations (paragraph 0009 wherein a transformed data unit may be split into two or more data groups by a physical block boundary). It would have been obvious to one of ordinary skill in the art the time the invention was made to modify the memory of Eilert to store data spanning two block of memory by splitting the data with the physical block boundary, as taught by Sinclair, since doing so allows for the efficient use of memory capacity.

Regarding Claim 26, Eilert in view of Sinclair discloses the system wherein the control circuitry causes a header having an indication of a memory location corresponding to the block of data (additional amount of data storing ECC and overhead related to the user data and the temporary cell group in which it is stored, paragraph 0004) to be stored within the first block of memory locations (paragraph 0009 wherein a transformed data unit may be split into two or more data groups by a physical block boundary and wherein a header is stored at the beginning of the block of data and therefore, it must be stored within the first data group when the block is split by the physical block boundary).

7. Claims 3-5, 9-11, 14-16, and 27-29 are rejected under 35 U.S.C. 103(a) as being unpatentable over Eilert (US 6,909,645) in view of Sinclair (US 2007/0088904) as applied to claims 1-3, 6-9, 12-14, 17-18, 21-22, and 25-27, above, and further in view of Zaidi (US 2006/0245236).

Regarding Claims 3, 9, 14, and 27, Eilert in view of Sinclair does not teach the memory device wherein the bit-alterable, non-volatile memory includes cells including a thin film chalcogenide alloy material. Zaidi discloses a phase change memory comprising a chalcogenide material. It would have been obvious to one of ordinary skill in the art at the time the invention was made to modify the invention of Eilert in view of Sinclair to include a chalcogenide alloy material in the composition of the phase change memory since this is a well known composition for this type of memory.

Regarding Claims 4, 10, 15, and 28, Zaidi discloses a chalcogenide alloy material comprising GeSbTe (paragraph 0058).

Regarding Claims 5, 11, 16, and 29, Zaidi discloses a chalcogenide alloy material comprising AgInSbTe (paragraph 0058).

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to MIDYS ROJAS whose telephone number is (571)272-4207. The examiner can normally be reached on M-TH 6:00am - 4:30pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Sanjiv Shah can be reached on (571) 272-4098. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Art Unit: 2185

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see <http://pair-direct.uspto.gov>. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

/Sanjiv Shah/
Supervisory Patent Examiner, Art Unit 2185

/Midys Rojas/
Examiner, Art Unit 2185

MR